

To our customers,

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## Old Company Name in Catalogs and Other Documents

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On April 1<sup>st</sup>, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR

## NP48N055ELE, NP48N055KLE NP48N055CLE, NP48N055DLE, NP48N055MLE, NP48N055NLE

### SWITCHING N-CHANNEL POWER MOS FET

#### DESCRIPTION

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

#### <R> ORDERING INFORMATION

| PART NUMBER                            | LEAD PLATING  | PACKING         | PACKAGE                           |
|--|---------------|-----------------|-----------------------------------|
| NP48N055ELE-E1-AY <sup>Note1, 2</sup>  | Pure Sn (Tin) | Tape 800 p/reel | TO-263 (MP-25ZJ) typ. 1.4 g       |
| NP48N055ELE-E2-AY <sup>Note1, 2</sup>  |               |                 | TO-263 (MP-25ZK) typ. 1.5 g       |
| NP48N055KLE-E1-AY <sup>Note1</sup>     |               |                 |                                   |
| NP48N055KLE-E2-AY <sup>Note1</sup>     | Sn-Ag-Cu      | Tube 50 p/tube  | TO-220 (MP-25) typ. 1.9 g         |
| NP48N055CLE-S12-AZ <sup>Note1, 2</sup> |               |                 | TO-262 (MP-25 Fin Cut) typ. 1.8 g |
| NP48N055DLE-S12-AY <sup>Note1, 2</sup> | Pure Sn (Tin) |                 | TO-220 (MP-25K) typ. 1.9 g        |
| NP48N055MLE-S18-AY <sup>Note1</sup>    |               |                 | TO-262 (MP-25SK) typ. 1.8 g       |
| NP48N055NLE-S18-AY <sup>Note1</sup>    |               |                 |                                   |

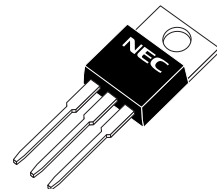
**Notes** 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Not for new design

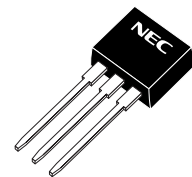
#### FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance  
 $R_{DS(on)1} = 17 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 24 \text{ A)}$   
 $R_{DS(on)2} = 21 \text{ m}\Omega \text{ MAX. (} V_{GS} = 5 \text{ V, } I_D = 24 \text{ A)}$   
 $R_{DS(on)3} = 24 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 24 \text{ A)}$
- Low input capacitance  
 $C_{iss} = 1970 \text{ pF TYP.}$
- Built-in gate protection diode

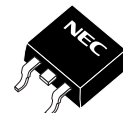
(TO-220)



(TO-262)



(TO-263)



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**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)**

|   |                       |             |    |
|---|-----------------------|-------------|----|
| Drain to Source Voltage (V <sub>GS</sub> = 0 V) | V <sub>DSS</sub>      | 55          | V  |
| Gate to Source Voltage (V <sub>DS</sub> = 0 V)  | V <sub>GSS</sub>      | ±20         | V  |
| Drain Current (DC) (T <sub>C</sub> = 25°C)      | I <sub>D(DC)</sub>    | ±48         | A  |
| Drain Current (pulse) <sup>Note1</sup>          | I <sub>D(pulse)</sub> | ±140        | A  |
| Total Power Dissipation (T <sub>A</sub> = 25°C) | P <sub>T</sub>        | 1.8         | W  |
| Total Power Dissipation (T <sub>C</sub> = 25°C) | P <sub>T</sub>        | 85          | W  |
| Channel Temperature                             | T <sub>ch</sub>       | 175         | °C |
| Storage Temperature                             | T <sub>stg</sub>      | -55 to +175 | °C |
| Single Avalanche Current <sup>Note2</sup>       | I <sub>AS</sub>       | 46/27/10    | A  |
| Single Avalanche Energy <sup>Note2</sup>        | E <sub>AS</sub>       | 2.1/73/100  | mJ |

**Notes 1.** PW ≤ 10 μs, Duty cycle ≤ 1%

**2.** Starting T<sub>ch</sub> = 25°C, R<sub>G</sub> = 25 Ω, V<sub>GS</sub> = 20 → 0 V (see **Figure 4.**)

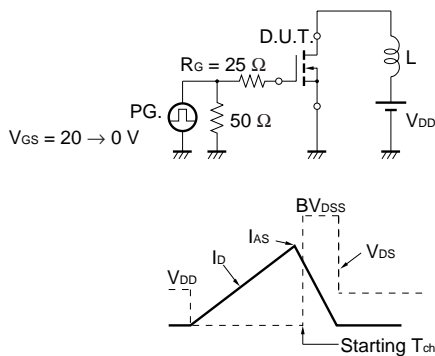
**THERMAL RESISTANCE**

|                                       |                       |      |      |
|---------------------------------------|-----------------------|------|------|
| Channel to Case Thermal Resistance    | R <sub>th(ch-C)</sub> | 1.76 | °C/W |
| Channel to Ambient Thermal Resistance | R <sub>th(ch-A)</sub> | 83.3 | °C/W |

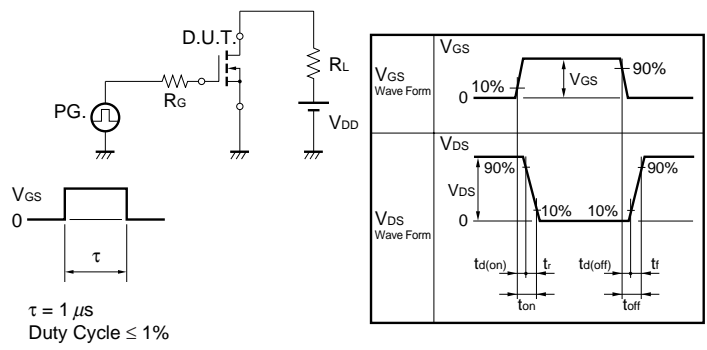
**ELECTRICAL CHARACTERISTICS (TA = 25°C)**

| CHARACTERISTICS                     | SYMBOL        | TEST CONDITIONS  | MIN. | TYP. | MAX.     | UNIT             |
|-------------------------------------|---------------|--|------|------|----------|------------------|
| Zero Gate Voltage Drain Current     | $I_{DSS}$     | $V_{DS} = 55\text{ V}, V_{GS} = 0\text{ V}$  |      |      | 10       | $\mu\text{A}$    |
| Gate Leakage Current                | $I_{GSS}$     | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$  |      |      | $\pm 10$ | $\mu\text{A}$    |
| Gate to Source Threshold Voltage    | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$  | 1.5  | 2.0  | 2.5      | V                |
| Forward Transfer Admittance         | $ y_{fs} $    | $V_{DS} = 10\text{ V}, I_D = 24\text{ A}$  | 13   | 25   |          | S                |
| Drain to Source On-state Resistance | $R_{DS(on)1}$ | $V_{GS} = 10\text{ V}, I_D = 24\text{ A}$  |      | 13   | 17       | $\text{m}\Omega$ |
|                                     | $R_{DS(on)2}$ | $V_{GS} = 5\text{ V}, I_D = 24\text{ A}$   |      | 16   | 21       | $\text{m}\Omega$ |
|                                     | $R_{DS(on)3}$ | $V_{GS} = 4.5\text{ V}, I_D = 24\text{ A}$   |      | 18   | 24       | $\text{m}\Omega$ |
| Input Capacitance                   | $C_{iss}$     | $V_{DS} = 25\text{ V},$<br>$V_{GS} = 0\text{ V},$<br>$f = 1\text{ MHz}$                    |      | 1970 | 3000     | pF               |
| Output Capacitance                  | $C_{oss}$     |  |      | 250  | 380      | pF               |
| Reverse Transfer Capacitance        | $C_{rss}$     |  |      | 130  | 240      | pF               |
| Turn-on Delay Time                  | $t_{d(on)}$   | $V_{DD} = 28\text{ V}, I_D = 24\text{ A},$<br>$V_{GS} = 10\text{ V},$<br>$R_G = 1\ \Omega$ |      | 17   | 38       | ns               |
| Rise Time                           | $t_r$         |  |      | 11   | 27       | ns               |
| Turn-off Delay Time                 | $t_{d(off)}$  |  |      | 54   | 110      | ns               |
| Fall Time                           | $t_f$         |  |      | 9.3  | 23       | ns               |
| Total Gate Charge                   | $Q_{G1}$      | $V_{DD} = 44\text{ V}, V_{GS} = 10\text{ V}, I_D = 48\text{ A}$                            |      | 40   | 60       | nC               |
|                                     | $Q_{G2}$      | $V_{DD} = 44\text{ V},$<br>$V_{GS} = 5\text{ V},$<br>$I_D = 48\text{ A}$                   |      | 21   | 32       | nC               |
| Gate to Source Charge               | $Q_{GS}$      |  |      | 7    |          | nC               |
| Gate to Drain Charge                | $Q_{GD}$      |  |      | 10   |          | nC               |
| Body Diode Forward Voltage          | $V_{F(S-D)}$  | $I_F = 48\text{ A}, V_{GS} = 0\text{ V}$   |      | 1.0  |          | V                |
| Reverse Recovery Time               | $t_{rr}$      | $I_F = 48\text{ A}, V_{GS} = 0\text{ V},$<br>$di/dt = 100\text{ A}/\mu\text{s}$            |      | 40   |          | ns               |
| Reverse Recovery Charge             | $Q_{rr}$      |  |      | 55   |          | nC               |

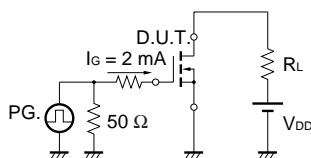
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



**TEST CIRCUIT 2 SWITCHING TIME**



**TEST CIRCUIT 3 GATE CHARGE**



TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

Figure1. DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

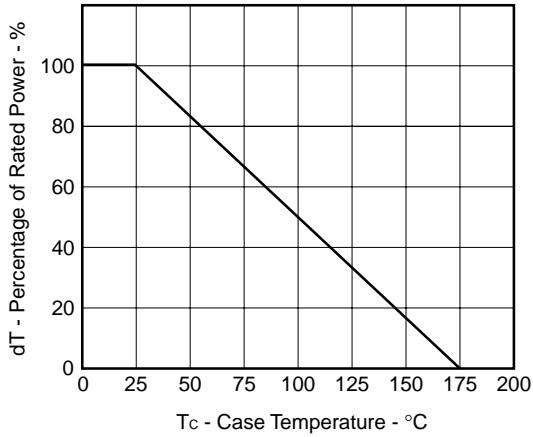


Figure2. TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

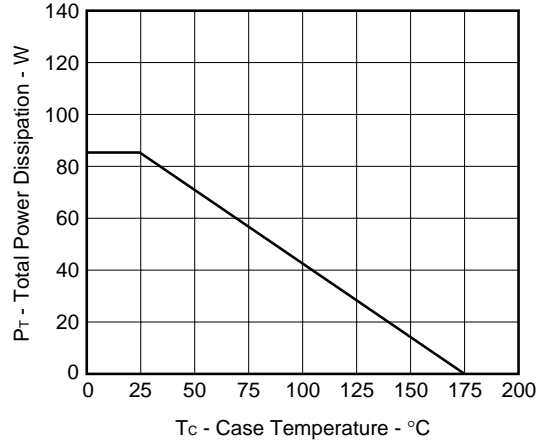


Figure3. FORWARD BIAS SAFE OPERATING AREA

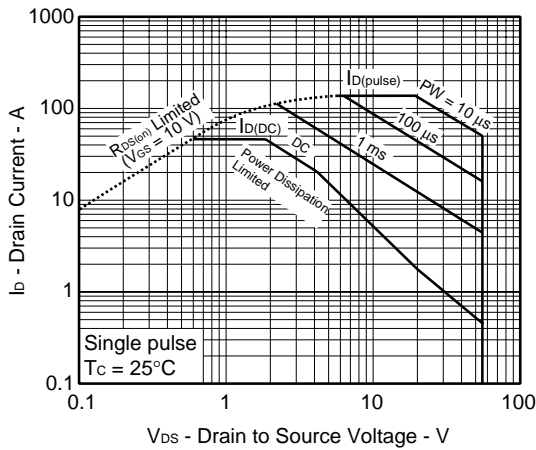


Figure4. SINGLE AVALANCHE ENERGY DERATING FACTOR

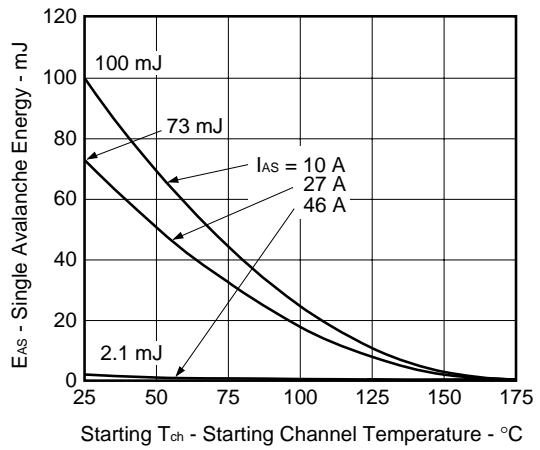


Figure5. TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

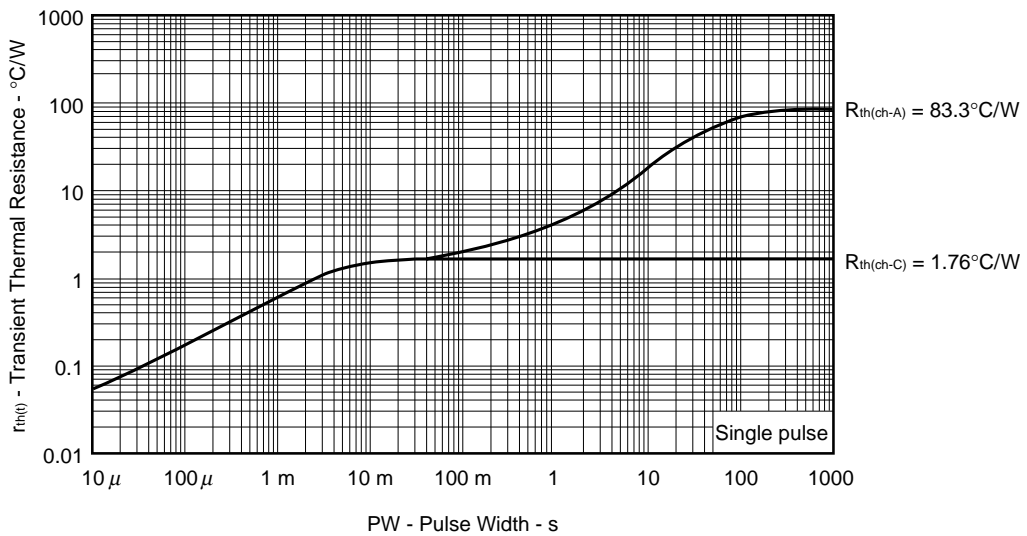


Figure6. FORWARD TRANSFER CHARACTERISTICS

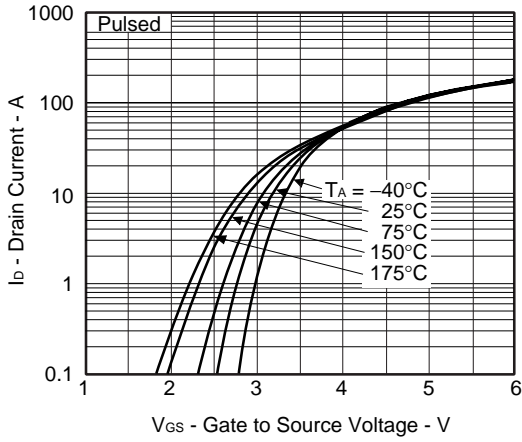


Figure7. DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

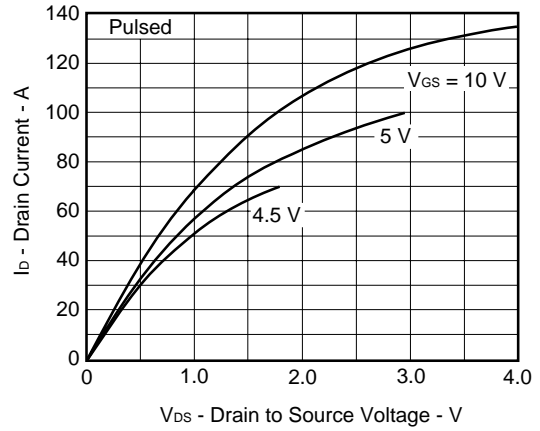


Figure8. FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

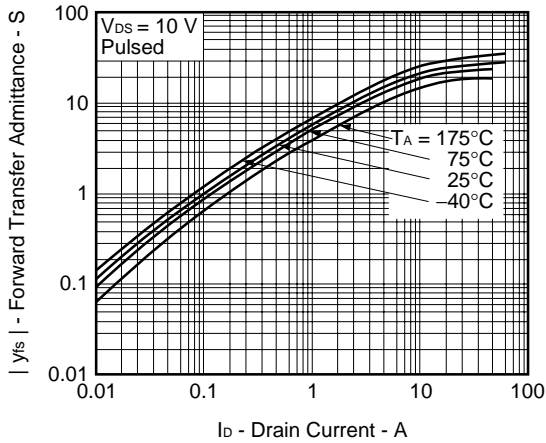


Figure9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

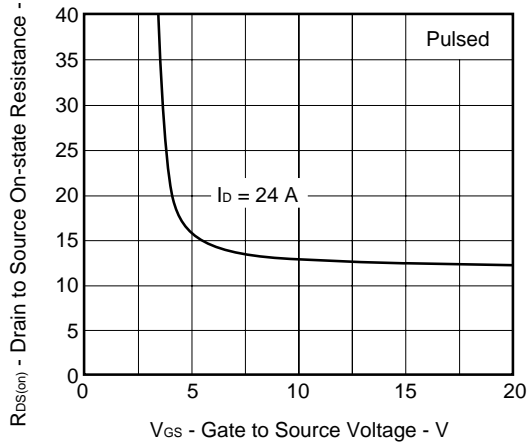


Figure10. DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

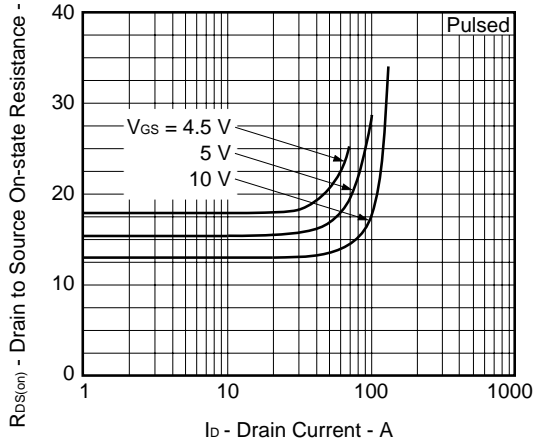


Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

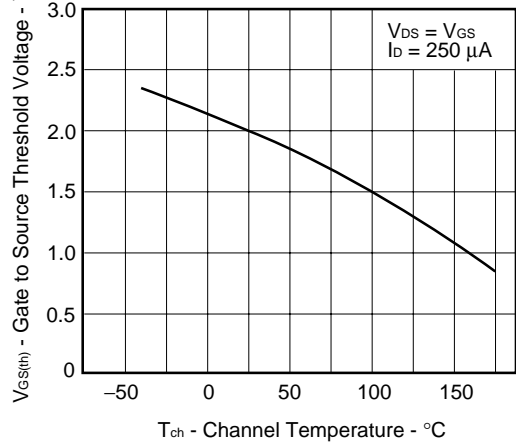


Figure12. DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

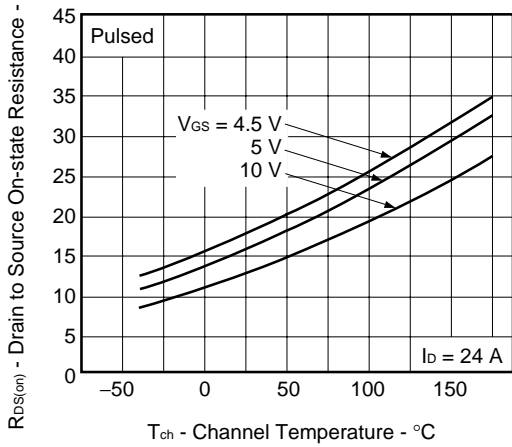


Figure13. SOURCE TO DRAIN DIODE FORWARD VOLTAGE

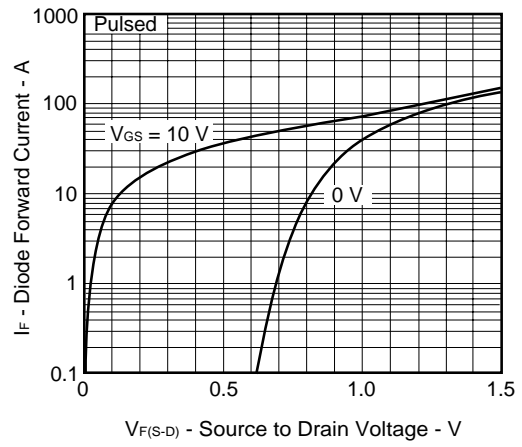


Figure14. CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

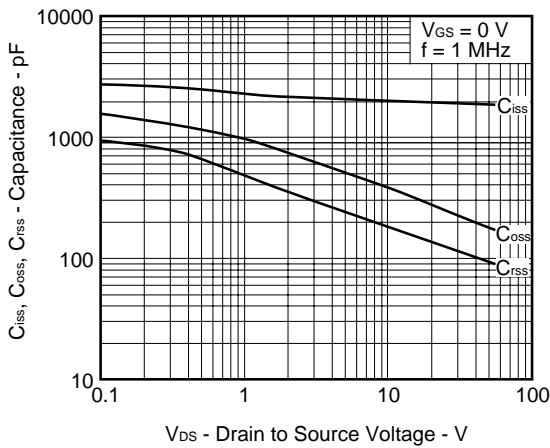


Figure15. SWITCHING CHARACTERISTICS

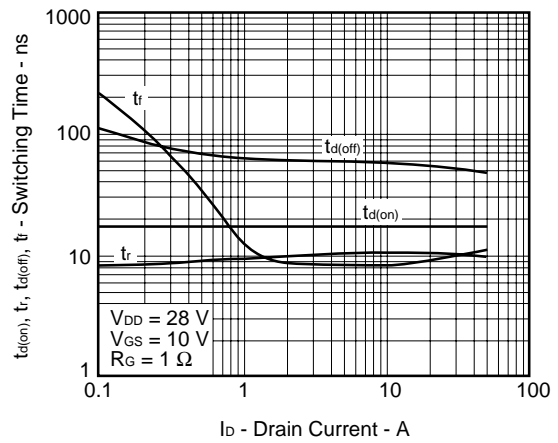


Figure16. REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

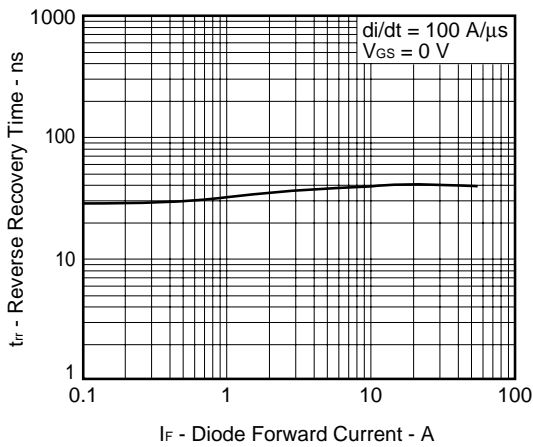
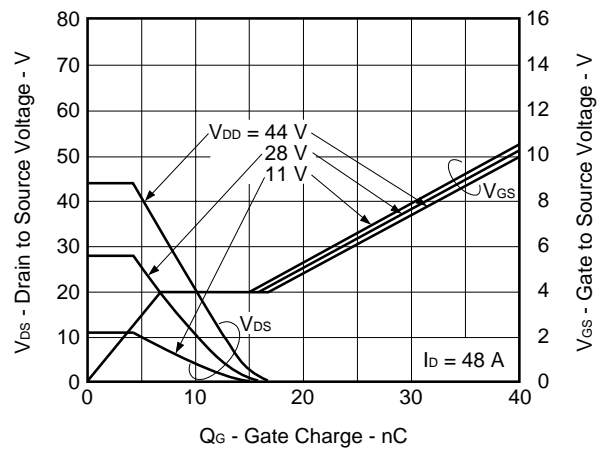


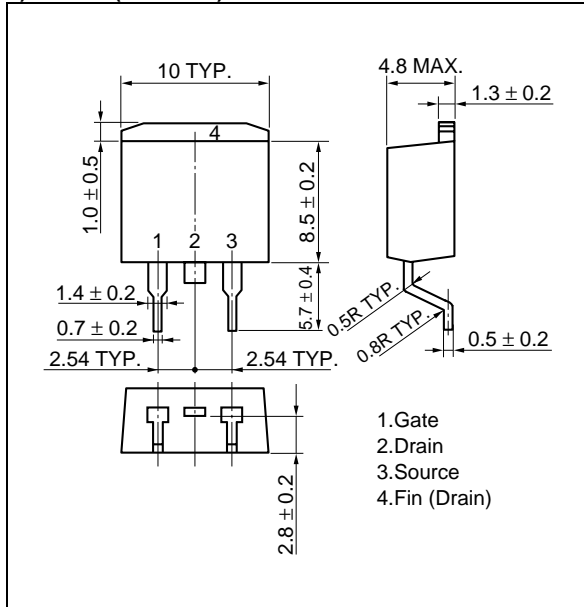
Figure17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS



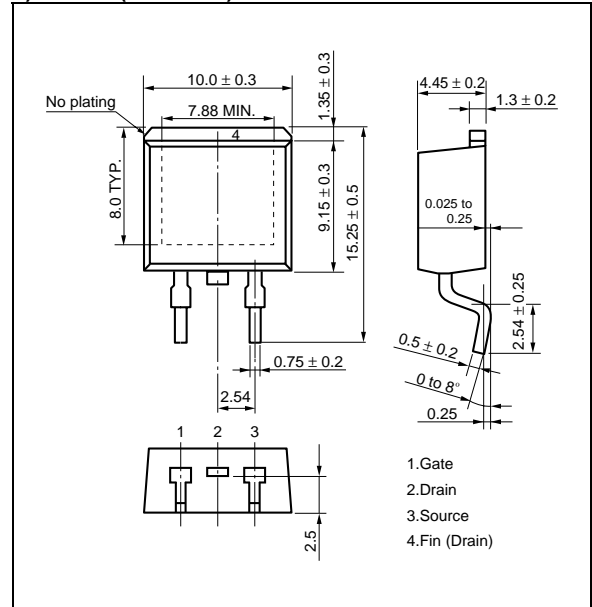


<R> PACKAGE DRAWINGS (Unit: mm)

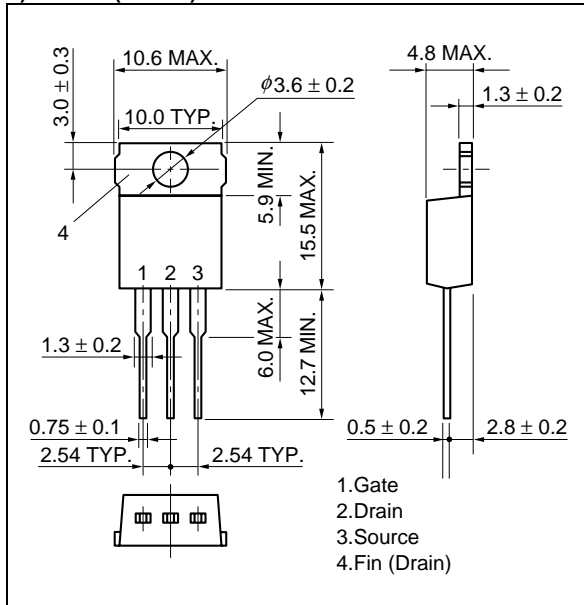
1) TO-263 (MP-25ZJ) <sup>Note</sup>



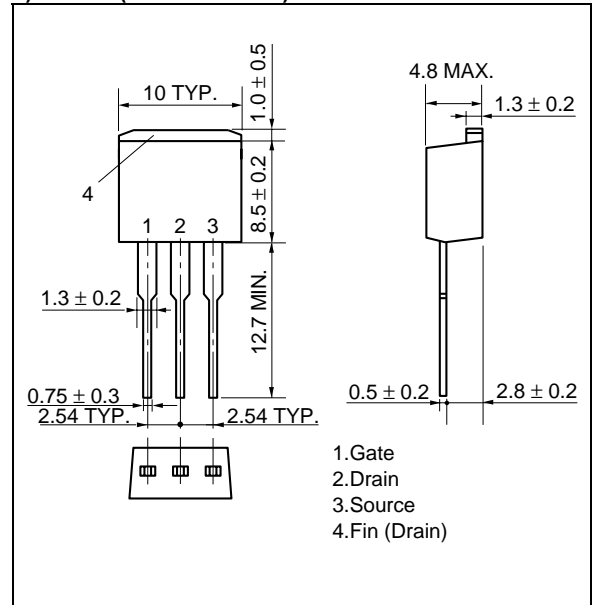
2) TO-263 (MP-25ZK)



3) TO-220 (MP-25) <sup>Note</sup>



4) TO-262 (MP-25 Fin Cut) <sup>Note</sup>

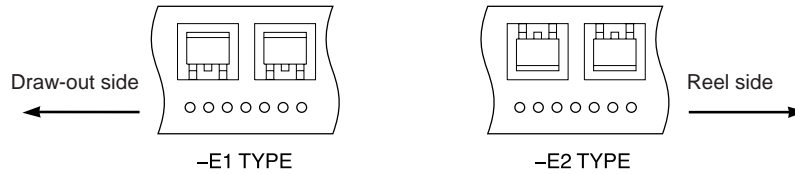


**Note** Not for new design

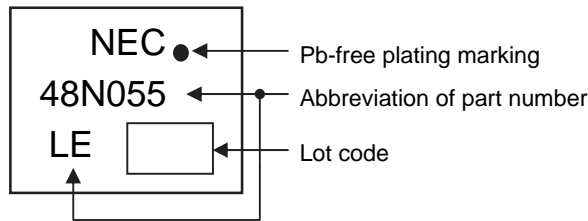


<R> **TAPE INFORMATION**

There are two types (-E1, -E2) of taping depending on the direction of the device.



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For technical information, see the following website.

Semiconductor Device Mount Manual (<http://www.necel.com/pkg/en/mount/index.html>)

| Soldering Method   | Soldering Conditions   | Recommended Condition Symbol |
|--|--|------------------------------|
| Infrared reflow<br>MP-25ZJ, MP-25ZK                        | Maximum temperature (Package's surface temperature): 260°C or below<br>Time at maximum temperature: 10 seconds or less<br>Time of temperature higher than 220°C: 60 seconds or less<br>Preheating time at 160 to 180°C: 60 to 120 seconds<br>Maximum number of reflow processes: 3 times<br>Maximum chlorine content of rosin flux (percentage mass): 0.2% or less | IR60-00-3                    |
| Wave soldering<br>MP-25, MP-25K, MP-25SK,<br>MP-25 Fin Cut | Maximum temperature (Solder temperature): 260°C or below<br>Time: 10 seconds or less<br>Maximum chlorine content of rosin flux: 0.2% (wt.) or less   | THDWS                        |
| Partial heating<br>MP-25ZJ, MP-25ZK,<br>MP-25K, MP-25SK    | Maximum temperature (Pin temperature): 350°C or below<br>Time (per side of the device): 3 seconds or less<br>Maximum chlorine content of rosin flux: 0.2% (wt.) or less  | P350                         |
| Partial heating<br>MP-25, MP-25 Fin Cut                    | Maximum temperature (Pin temperature): 300°C or below<br>Time (per side of the device): 3 seconds or less<br>Maximum chlorine content of rosin flux: 0.2% (wt.) or less  | P300                         |

**Caution Do not use different soldering methods together (except for partial heating).**

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"Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).

"Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).